



# Application

- Lithography for sub 10 nm resolution
- Template fabrication for Nanoimprint Lithography
- Lithography for high aspect ratio nanostructures
- Highly accurate and flexible fabrication for nanoelectronics & nanophotonics
- Nanostructures for biotechnology

#### Description



## Description

AMO offers a wide range of readily available EBL processes on many different substrate types, substrate sizes and applications. This includes processes for both positive and negative tone resists (PMMA, UV6, HSQ, UVN30). Processes suitable to be followed by a RIE etching or a lift-off process, both also offered by AMO, are at hand. For the fabrication of high aspect ratio nanostructures special processes utilising super critical resist drying can be used. Processes using megasonic assisted development are also available. In addition to these ready-to-use processes AMO also offers on request the development of EBL processes for the special needs of our customers.

#### **Specification**

Parameter	Positive Resist	Negative Resist	
Resist	PMMA, UV6	HSQ, UVN30	
Acceleration Voltage	50 kV, 100 kV	50 kV, 100 kV	
Resolution	Sub 15 nm	Sub 10 nm	
Substrate Material	Silicon, SOI, GaAs, Quartz, Ta2O5, Si3N4, Metallic surfaces: Ti, Cr, W, TiN, Ni, Al, NiSi		
Substrate Size	from samples of 10x10 mm <sup>2</sup> up to 8" wafer		
Tools	Raith EBPG 5200 (EB system), SC Fluids (super critical drying)		
Pattern Transfer	RIE etching, lift-off	RIE etching	

### Contact

Dipl.-Ing. Michael Möller moeller@amo.de

#### AMO GmbH

Gesellschaft für Angewandte Mikro- und Optoelektronik mbH Otto-Blumenthal-Straße 25 52074 Aachen Germany

#### Phone

+49 241 88 67-125 www.amo.de